

NCE N-Channel Super Trench Power MOSFET

Description

The NCEP1216AS uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{\text{DS(ON)}}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

General Features

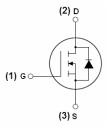
• V_{DS} =120V, I_D =16A $R_{DS(ON)}$ =8.7m Ω (typical) @ V_{GS} =10V $R_{DS(ON)}$ =10.0m Ω (typical) @ V_{GS} =4.5V

- Excellent gate charge x R_{DS(on)} product(FOM)
- Very low on-resistance R_{DS(on)}
- 150 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

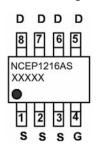
Application

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

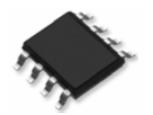
100% UIS TESTED!



Schematic diagram



Marking and pin assignment



SOP-8 top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP1216AS	NCEP1216AS	SOP-8	Ø330mm	12mm	2500 units

Absolute Maximum Ratings (T_A=25 ℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	120	V
Gate-Source Voltage	V _G S	±20	V
Drain Current-Continuous	I _D	16	А
Drain Current-Continuous(T _C =100°C)	I _D (100℃)	11.3	А
Pulsed Drain Current	I _{DM}	64	А
Maximum Power Dissipation	P _D	3.5	W
Single pulse avalanche energy (Note 5)	E _{AS}	210	mJ
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 150	$^{\circ}$ C

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	36	°C/W
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Electrical Characteristics (T_A=25 °C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	120	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =120V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1.0	1.7	2.2	V
Drain-Source On-State Resistance Forward Transconductance	R _{DS(ON)}	V _{GS} =10V, I _D =16A	-	8.7	10.3	mΩ
		V _{GS} =4.5V, I _D =16A	-	10.0	10.6	mΩ
Forward Transconductance	g FS	V _{DS} =10V,I _D =16A	50	-	-	S
Dynamic Characteristics (Note4)	·		•			
Input Capacitance	C _{lss}	\/ -60\/\/ -0\/	-	4960		PF
Output Capacitance	Coss	V_{DS} =60V, V_{GS} =0V, F=1.0MHz	-	389		PF
Reverse Transfer Capacitance	C _{rss}	r=1.0lvln2	-	25.3		PF
Switching Characteristics (Note 4)	·		•			
Turn-on Delay Time	t _{d(on)}		-	15.4	-	nS
Turn-on Rise Time	t _r	V _{DD} =60V,I _D =16A	-	9.9	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{G} =1.6 Ω	-	42.9	-	nS
Turn-Off Fall Time	t _f		-	5.5	-	nS
Total Gate Charge	Qg	V -60VI -16A	-	63.8	-	nC
Gate-Source Charge	Q _{gs}	V_{DS} =60V, I_{D} =16A, V_{GS} =10V	-	16.5	-	nC
Gate-Drain Charge	Q_{gd}	V _{GS} =10V	-	8.8	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =16A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	16	Α
Reverse Recovery Time	t _{rr}	$T_J = 25^{\circ}C, I_F = I_S$	-	105	-	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	200	-	nC

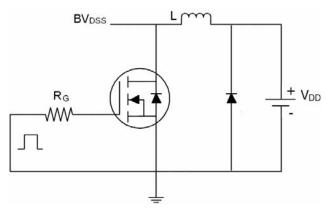
Notes:

- ${\bf 1.}\ {\bf Repetitive}\ {\bf Rating:}\ {\bf Pulse}\ {\bf width}\ {\bf limited}\ {\bf by}\ {\bf maximum}\ {\bf junction}\ {\bf temperature}.$
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25 $^{\circ}\text{C}$,VDD=50V,VG=10V,L=0.5mH,Rg=25 Ω

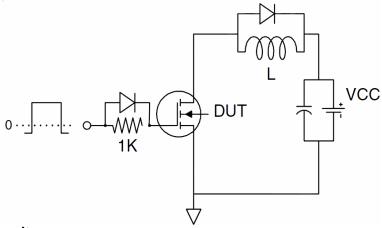


Test Circuit

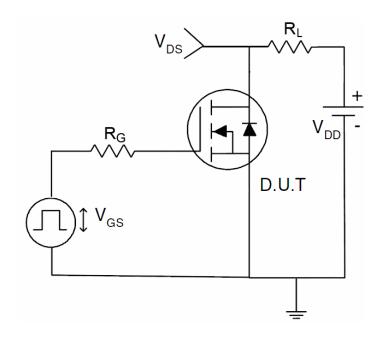
1) E_{AS} test Circuit



2) Gate charge test Circuit



3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics

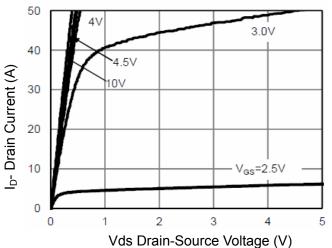


Figure 1 Output Characteristics

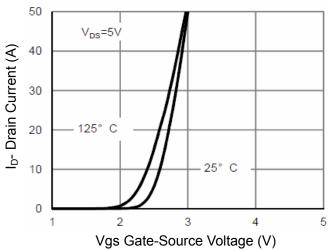


Figure 2 Transfer Characteristics

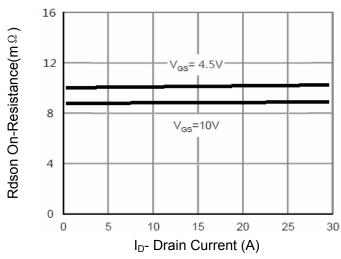


Figure 3 Rdson- Drain Current

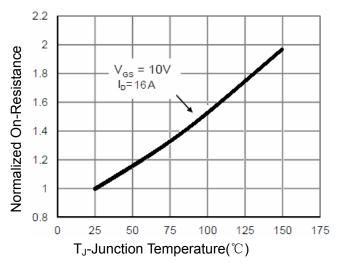
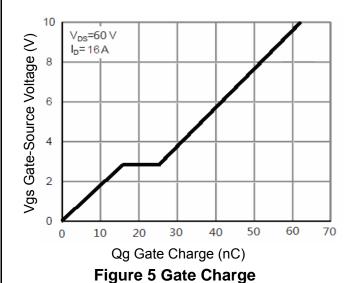


Figure 4 Rdson-Junction Temperature



1.0E+01 (V) 1.0E+00 1.0E-01 1.0E-02 1.0E-03 1.0E-03 1.0E-04 1.0E-05 0.0 0.2 0.4 0.6 0.8 1.0 Vsd Source-Drain Voltage (V)

Figure 6 Source- Drain Diode Forward



lp- Drain Current (A)

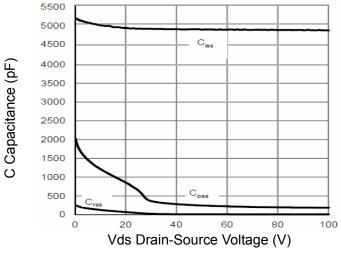


Figure 7 Capacitance vs Vds

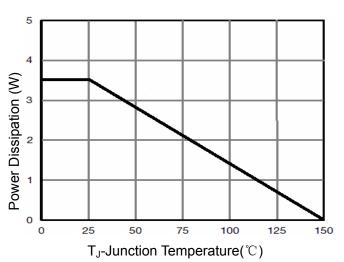


Figure 9 Power De-rating

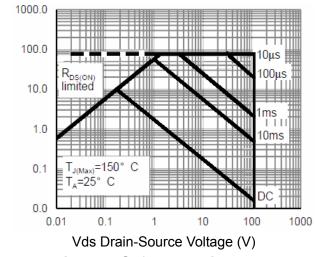


Figure 8 Safe Operation Area

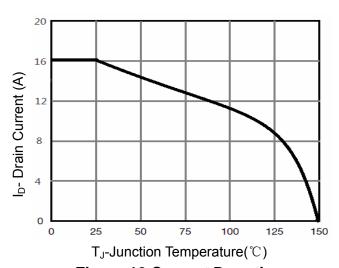
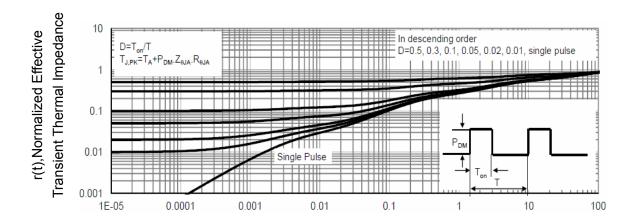


Figure 10 Current De-rating

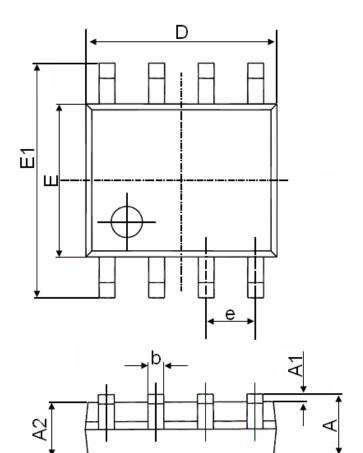


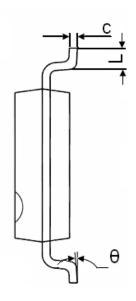
Square Wave Pluse Duration(sec)

Figure 11 Normalized Maximum Transient Thermal Impedance



SOP-8 Package Information





Correle ed	Dimensions In Millimeters		Dimensions In Inches	
Symbol	Min.	Max.	Min.	Max.
А	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
С	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
е	1.270(BSC)		0.050	(BSC)
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

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NCEP1216AS

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